# Improvement of the $\gamma$-TiAl Oxidation Resistance by Aluminizing 

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## Introduction

In combination with good stiffness and strength, titanium aluminides offer the potential for component weight savings on the order of $50 \%$ over superalloys and steels. The target application temperature range for Ti-Al intermetallics is $600-1000^{\circ} \mathrm{C}$. However, the use of TiAl based components above $800^{\circ} \mathrm{C}$ is limited especially by their poor environmental resistance. The present study deals with aluminizing as a possible method for improving $\gamma$-TiAl high-temperature oxidation resistance.

## Experimental procedure

The pack-cementation coating process was used to aluminize the surface region of a $\gamma$ TiAl alloy to a potential alumina-forming phase. Coating was formed by burying $\gamma-\mathrm{TiAl}$ coupons for 5 h at $800^{\circ} \mathrm{C}$ in a powder mixture consisting of $5 \mathrm{wt} . \% \mathrm{Al}, 0.5 \mathrm{wt} . \% \mathrm{NH}_{4} \mathrm{Cl}$, and balance $\mathrm{Al}_{2} \mathrm{O}_{3}$. The aluminized samples were tested at 800,900 and $1000^{\circ} \mathrm{C}$ in laboratory air for up to 100 h .


After oxidation
After aluminizing


The aluminizing treatment resulted in the formation of a $30 \mu \mathrm{~m}$ thick adherent and free of cracks $\mathrm{TiAl}_{3}$ layer. This layer interdiffused rapidly with the $\gamma$-TiAl substrate during oxidation, leading to the formation of a $\mathrm{TiAl}_{2}$ layer at the oxide $/ \mathrm{TiAl}_{3}$ interface.
The $\mathrm{TiAl}_{3}$ coating on $\gamma$-TiAl showed excellent oxidation resistance in air at 900 and $1000^{\circ} \mathrm{C}$ for 10 h , forming a protective and adherent $\mathrm{Al}_{2} \mathrm{O}_{3}$ scale. At $800^{\circ} \mathrm{C}$, the oxidation process induced the formation of a thicker $\mathrm{Al}_{2} \mathrm{O}_{3}$ scale containing $\mathrm{TiO}_{2}$ grains. At 800,900 , and $1000^{\circ} \mathrm{C}$, the oxide was $\alpha+\theta-\mathrm{Al}_{2} \mathrm{O}_{3}$ as confirmed by Fluorescence spectroscopy analysis.


Oxidation behavior of $\mathrm{TiAl}_{3}$ and $\mathrm{TiAl}_{2}$ phases
To study the oxidation behavior of the different TiAl phases, a short term oxidation test was performed at $900^{\circ} \mathrm{C}$ on the cross section of the $\gamma$-TiAl substrate coated and oxidized at $900^{\circ} \mathrm{C}$ for 10 h in air. Surprisingly, the $\alpha-$ $\mathrm{Al}_{2} \mathrm{O}_{3}$ scale formed on the $\mathrm{TiAl}_{2}$ phase was significantly thinner and free of whiskers compared to the metastable $\theta$ $\mathrm{Al}_{2} \mathrm{O}_{3}$ formed on the most promising oxidation resistant $\mathrm{TiAl}_{3}$ phase.

100 h oxidation at $900^{\circ} \mathrm{C}$ in air
When the oxidation time was prolonged to 100 h , both the oxidation and interdiffusion processes induced a decrease of the $\mathrm{TiAl}_{3}$ layer thickness and an increase of the $\mathrm{TiAl}_{2}$ layer thickness. From 10 to 50 h exposure time, the oxide scale was only composed of $\mathrm{Al}_{2} \mathrm{O}_{3}$. After 100 h oxidation, the alumina-forming $\mathrm{TiAl}_{3}$ layer was only $7 \mu \mathrm{~m}$ thick, and some $\mathrm{TiO}_{2}$ grains were formed in the $\mathrm{Al}_{2} \mathrm{O}_{3}$ layer.


## Conclusion

- An adherent oxidation resistant Al-diffusion coating was successfully formed on the surface of a $\gamma$-TiAl alloy using the pack-cementation technique. The protection was provided by aluminizing of the $\gamma-\mathrm{TiAl}$ substrate to its highest aluminide, the alumina-forming $\mathrm{TiAl}_{3}$ phase. - After 10 h oxidation at 900 and $1000^{\circ} \mathrm{C}$ in air, a protective and adherent $\mathrm{Al}_{2} \mathrm{O}_{3}$ layer identified as $\alpha+\theta$ phase was formed on the $\mathrm{TiAl}_{3}$ coating. The effectiveness of the $\mathrm{TiAl}_{3}$ coating was seriously affected by the $\mathrm{TiAl}_{2}$ phase which develops during oxidation, and after 100 h oxidation at $900^{\circ} \mathrm{C}$ in air, the formation of a protective $\mathrm{Al}_{2} \mathrm{O}_{3}$ layer was no longer maintained.


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